onsemi

MOSFET – Power, Dual N-Channel, for 1-2 Cells Lithium-ion Battery Protection

24 V, 45 mΩ, 6 A

EFC4612R-S

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1–2 cells lithium–ion battery applications.

Features

- 2.5 V Drive
- Common-Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halide Free and RoHS Compliant

Applications

• 1-2 Cells Lithium-ion Battery Charging and Discharging Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at $T_A = 25^{\circ}C$

| Parameter | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Source to Source Voltage | V _{SSS} | 24 | V |
| Gate to Source Voltage | V _{GSS} | ±12 | V |
| Source Current (DC) | ۱ _S | 6 | А |
| Source Current (Pulse) PW \leq 10 μ s, duty cycle \leq 1% | I _{SP} | 60 | A |
| Total Dissipation (Note 2) | PT | 1.6 | W |
| Junction Temperature | Tj 150 | | °C |
| Storage Temperature | Tstg | –55 to +150 | °C |

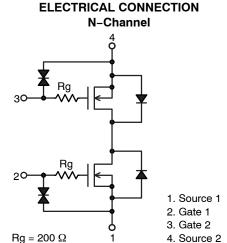
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

| Parameter | Symbol | Value | Unit |
|------------------------------|-----------------|-------|------|
| Junction to Ambient (Note 1) | $R_{\theta JA}$ | 78.1 | °C/W |

1. Surface mounted on ceramic substrate (5000 $\text{mm}^2 \times 0.8$ mm).

| V _{SSS} | R _{SS(on)} Max | I _S Max |
|------------------|--------------------------------------|--------------------|
| 24 V | 45 mΩ @ 4.5 V | 6 A |
| | 48 mΩ @ 4.0 V | |
| | $50~\text{m}\Omega @ 3.7~\text{V}$ | |
| | $57 \text{ m}\Omega @ 3.1 \text{ V}$ | |
| | 72 m Ω @ 2.5 V | |







DIAGRAM

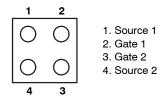
WLCSP4, 1.3 × 1.3 / EFCP1313-4CC-037 CASE 567DP

| | FNY MZZ | |
|---|------------|--|
| 0 | | |

FN = Specific Device Code

- Y = Year
- M = Month
- ZZ = Assembly Lot Number

PIN CONNECTIONS



ORDERING INFORMATION

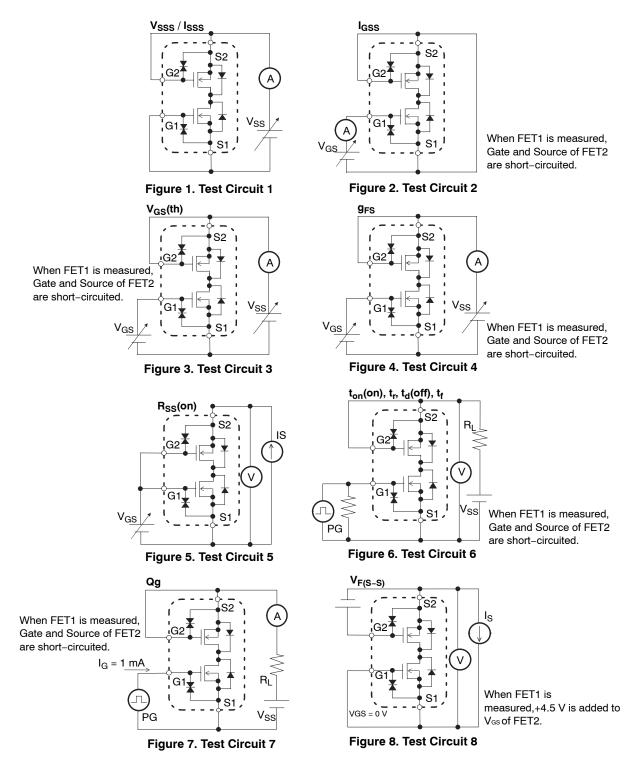
See detailed ordering and shipping information on page 6 of this data sheet.

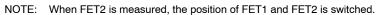
ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$

| | | | | Value | | | |
|--|-----------------------|--|------------|-------|-----|-----|------|
| Parameter | Symbol | Conditions | | Min | Тур | Мах | Unit |
| Source to Source Breakdown Voltage | V(BR)SSS | I _S = 1 mA, V _{GS} = 0 V | (Figure 1) | 24 | - | - | V |
| Zero-Gate Voltage Source Current | I _{SSS} | V_{SS} = 20 V, V_{GS} = 0 V | (Figure 1) | - | - | 1 | μΑ |
| Gate to Source Leakage Current | I _{GSS} | V_{GS} = ±8 V, V_{SS} = 0 V | (Figure 2) | - | - | ±10 | μA |
| Gate Threshold Voltage | V _{GS} (th) | V _{SS} = 10 V, I _S = 1 mA | (Figure 3) | 0.5 | - | 1.3 | V |
| Forward Transconductance | 9 _{FS} | V _{SS} = 10 V, I _S = 3 A | (Figure 4) | - | 3.1 | - | S |
| Static Source to Source On-State Resistance | R _{SS} (on)1 | V_{GS} = 4.5 V, I _S = 3 A | (Figure 5) | 24 | 39 | 45 | mΩ |
| | R _{SS} (on)2 | V_{GS} = 4.0 V, I _S = 3 A | (Figure 5) | 25 | 41 | 48 | mΩ |
| | R _{SS} (on)3 | V_{GS} = 3.7 V, I _S = 3 A | (Figure 5) | 27.5 | 43 | 50 | mΩ |
| | R _{SS} (on)4 | $V_{GS} = 3.1 \text{ V}, I_{S} = 3 \text{ A}$ | (Figure 5) | 31.5 | 48 | 57 | mΩ |
| | R _{SS} (on)5 | V_{GS} = 2.5 V, I _S = 3 A | (Figure 5) | 33.5 | 58 | 72 | mΩ |
| Turn–ON Delay Time | t _d (on) | $V_{SS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V},$ | (Figure 6) | - | 20 | - | ns |
| Rise Time | t _r | I _S = 3 A | | - | 230 | - | ns |
| Turn-OFF Delay Time | t _d (off) | | | - | 130 | - | ns |
| Fall Time | t _f | | | - | 210 | - | ns |
| Total Gate Charge | Qg | V_{SS} = 10 V, V_{GS} = 4.5 V, I_{S} = 6 A | (Figure 7) | - | 7 | - | nC |
| Forward Source to Source Voltage | V _{F(S-S)} | I _S = 3 A, V _{GS} = 0 V | (Figure 8) | - | 0.8 | 1.2 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

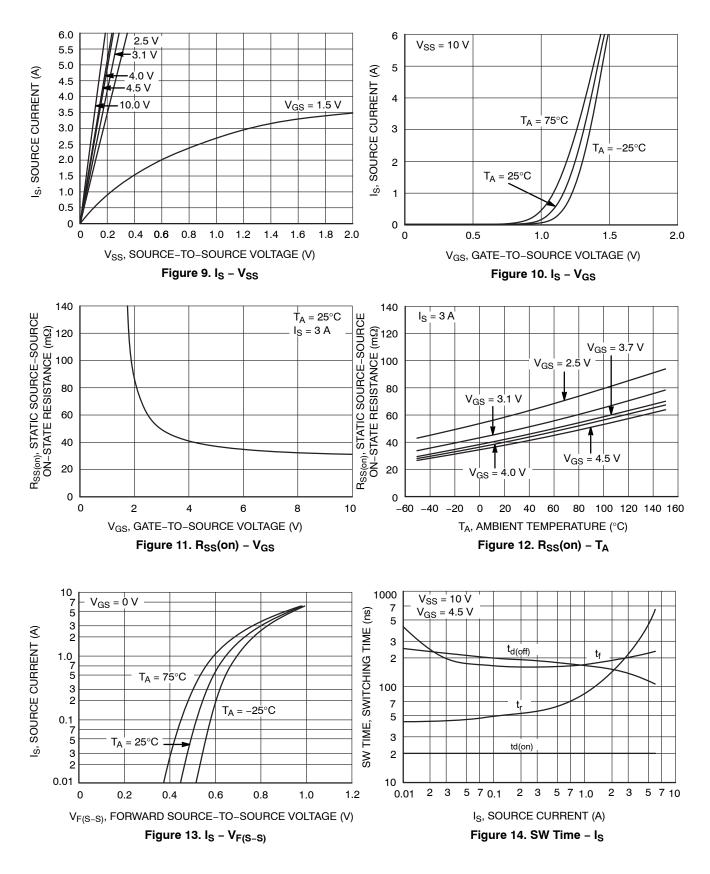
Test Circuit are Example of Measuring FET1 Side





EFC4612R-S

TYPICAL CHARACTERISTICS



EFC4612R-S

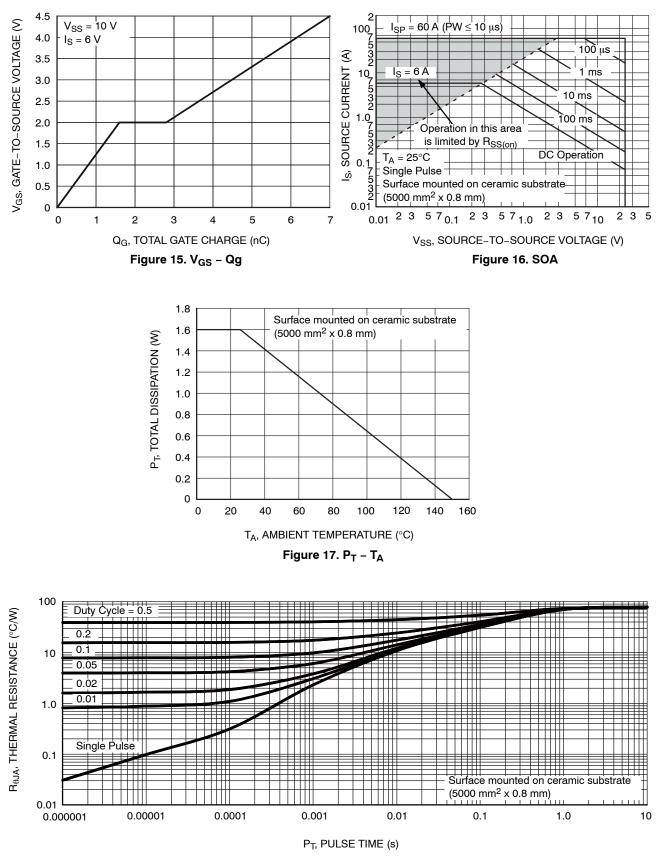


Figure 18. $R_{\theta JA}$ – Pulse Time

EFC4612R-S

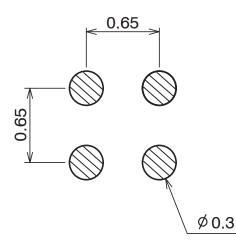
ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] (Qty / Packing) |
|---------------|---------|---|---------------------------------------|
| EFC4612R-S-TR | FN | WLCSP4, 1.3 ×1.3 / EFCP1313-4CC-037 (Pb-Free and Halide Free) | 5000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

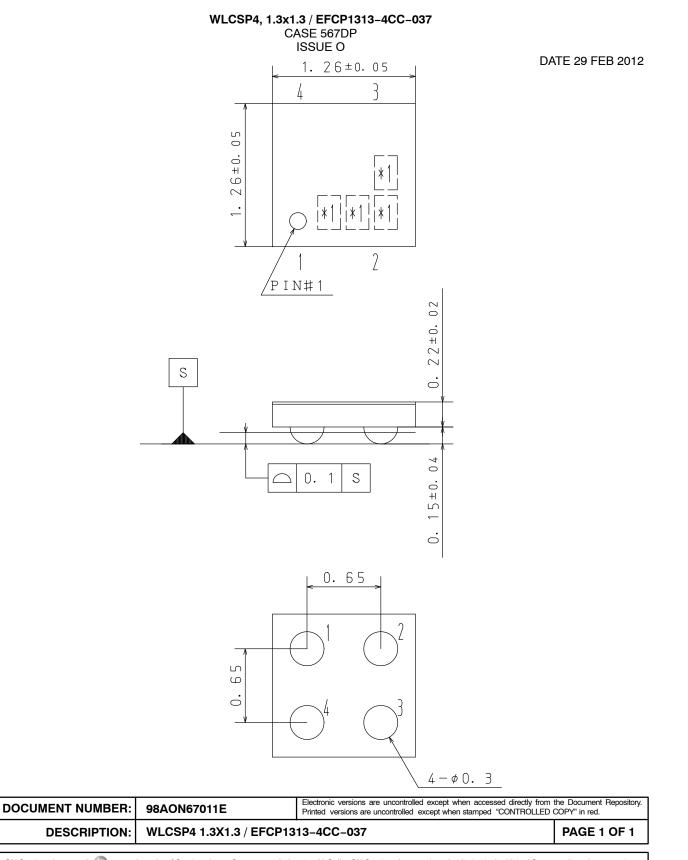
PACKAGE DIMENSION

(Unit: mm)









ON Semiconductor and () are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative